## FABRICATION AND CHARACTERIZATION OF HYBRID POLYMER SOLAR CELL

TOONG WAY YUN

# DISSERTATION SUBMITTED IN FULFILLMENT OF THE REQUIREMENT FOR THE DEGREE OF MASTER OF SCIENCE

# DEPARTMENT OF PHYSICS FACULTY OF SCIENCE UNIVERSITY OF MALAYA KUALA LUMPUR

2012

## **UNIVERSITI MALAYA**

### **ORIGINAL LITERARY WORK DECLARATION**

Name of Candidate: Toong Way Yun

(I.C/Passport No: 850907-06-5138)

Registration/Matric No: SGR090061

Name of Degree: Master of Science (Dissertation)

Title of Project Paper/Research Report/Dissertation/Thesis ("this Work"):

FABRICATION AND CHARACTERIZATION OF HYBRID POLYMER SOLAR CELL

Field of Study: Organic Electronics

I do solemnly and sincerely declare that:

- (1) I am the sole author/writer of this Work;
- (2) This Work is original;
- (3) Any use of any work in which copyright exists was done by way of fair dealing and for permitted purposes and any excerpt or extract from, or reference to or reproduction of any copyright work has been disclosed expressly and sufficiently and the title of the Work and its authorship have been acknowledged in this Work;
- (4) I do not have any actual knowledge nor do I ought reasonably to know that the making of this work constitutes an infringement of any copyright work;
- (5) I hereby assign all and every rights in the copyright to this Work to the University of Malaya ("UM"), who henceforth shall be owner of the copyright in this Work and that any reproduction or use in any form or by any means whatsoever is prohibited without the written consent of UM having been first had and obtained;
- (6) I am fully aware that if in the course of making this Work I have infringed any copyright whether intentionally or otherwise, I may be subject to legal action or any other action as may be determined by UM.

Candidate's Signature:

Date:

Subscribed and solemnly declared before, Witness's Signature:

Date:

Name: Dr. Khaulah Sulaiman Designation: Senior Lecturer

#### **ABSTRACT**

The easy fabrication method, tunable physical and chemical properties and costeffective fabrication process, makes organic solar cells (OSC) very attractive in photovoltaic application. Nonetheless, the device performance is limited due to the low charge mobility of the organic semiconductors that results in a less efficient of charge transport to the respective electrodes. In order to address such problems, hybrid polymer solar cells based on bulk heterojunction (BHJ) structure, which composed of a combination of both organic and inorganic semiconductors are employed. However, the BHJ device performances are strongly dependent on good processing conditions, especially enhancement of photons absorption as well as the improvement of charge transport properties. Hence, the involved parameters and properties should be well optimized.

This dissertation describes the study of effects of blend composition and types of acceptor materials used on the optical, structural, morphological as well as the electrical properties of the three different hybrid BHJ systems. The hybrid materials consist of a blend of p-type conjugated polymer of poly(3-hexylthiophene) (P3HT) and n-type inorganic metal oxide nanoparticles, namely, zinc oxide (ZnO), titanium dioxide (TiO<sub>2</sub>) and yttrium oxide  $(Y_2O_3)$ . The optical, structural and morphological characterizations of the blend thin films using UV-Visible absorption spectroscopy, X-ray diffraction (XRD) spectroscopy, Atomic Force Microscopy (AFM) and Field-effect Scanning Electron Microscopy (FESEM) are discussed. Furthermore, the co-relation of the thin film property with the device performance is presented. The results show that the device performance has been improved by optimizing the blend composition. This is due to an enhancement in light absorption in broader wavelength regime and improved charge transport through the formation of interpenetrating bicontinous pathway for the holes and electrons to reach the respective electrodes. These results are supported by the observation of the AFM and FESEM images of the increment in RMS roughness and formation of phase separation features in the blends. Besides, the well dispersion of inorganic nanoparticles over P3HT yields a larger interfacial area for charge carrier generation. Among the three hybrid systems investigated, P3HT:ZnO device performs the best with an optimal blend composition of 3% of ZnO nanoparticles in blend.

In order to further improve the device performances, ZnO sol-gel synthesis route has been utilized to produce a better mixing blend of P3HT and ZnO. Additionally, several approaches have been employed, namely modifying the sol content in blends, varying the annealing temperature, and inserting an additional ZnO buffer layer between the active layer and cathode. An optimal annealing treatment offers improved optical absorption properties and more uniform film surface morphology with eliminated redundant large pores and grain agglomerations. The role of the ZnO buffer layer in the blend system can be seen as an agent in facilitating the electron collection from the active layer to the cathode. The results indicate that the device efficiency has been improved by about 5 times for P3HT:ZnO sol gel device with optimized sol content (0.1ml sol), annealed at an optimized temperature of 100°C with additional ZnO buffer layer, compared to the P3HT:ZnO nanoparticles-based device.

#### ABSTRAK

Fabrikasi yang mudah, ciri-ciri fizikal dan kimia bolehlaras dan kos efektif proses fabrikasi, telah menyebabkan sel suria organik (OSC) amat menarik dalam bidang penggunaan fotovoltaik. Walau bagaimanapun, prestasi peranti menjadi terbatas disebabkan oleh kelincahan pembawa cas yang rendah bagi semikonduktor organik yang mengakibatkan angkutan cas ke elektrod menjadi kurang cekap. Dalam usaha untuk menangani masalah tersebut, sel suria polimer hibrid berasaskan struktur simpang-hetero pukal (BHJ) yang terdiri daripada kombinasi semikonduktor organik dan bukan organic telah digunapakai. Namun demikian, prestasi peranti amat bergantung kepada keadaan pemprosesan yang baik, terutamnya peningkatan serapan foton serta penambah-baikan sifat angkutan. Oleh yang demikian, parameter dan sifat yang terlibat perlu dioptimakan dengan sebaiknya.

Disertasi ini menerangkan kesan komposisi campuran dan jenis bahan penerima yang digunakan terhadap ciri-ciri optik, struktur, morfologi serta sifat elektrik bagi tiga sistem hybrid BHJ berbeza. Bahan hybrid terdiri daripada campuran bahan jenis-p polimer berkonjugat (3-hexylthiophene) (P3HT) dan bahan jenis-n nanopartikel oksida logam bukan organik, iaitu zink oksida (ZnO), titanium dioksida (TiO<sub>2</sub>) dan yttrium oksida (Y<sub>2</sub>O<sub>3</sub>). Pencirian optik, struktur dan morfologi dibincangkan bagi filem nipis campuran yang menggunakan spektroskopi serapan ultraungu-cahaya-nampak (UV-Vis), spektroskopi belauan sinar-X (XRD), mikroskop daya atom (AFM) dan mikroskopi electron daya imbasan (FESEM). Malahan, hubung-kait antara sifat filem nipis dengan prestasi peranti juga dibentangkan. Dapatan kajian menunjukkan bahawa prestasi peranti telah ditingkatkan dengan mengoptimumkan komposisi campuran. Ini disebabkan oleh peningkatan dalam penyerapan cahaya di rantau gelombang yang lebih luas dan meningkatnya angkutan cas melalui pembentukan laluan dwi-berterusan saling-menyusup untuk pergerakan lohong dan electron sampai ke elektrod. Hasil ini disokong oleh pemerhatian terhadap imej AFM and FESEM yang mana terdapat kenaikan dalam nilai kekasaran RMS dan pembentukan pemisahan fasa dalam filem campuran. Selain itu, penyerakan nanopartikel bukan organik yang seragam dalam P3HT menghasilkan kawasan sempadan antara-fasa yang lebih luas untuk menjana pembawa cas. Antara tiga jenis sistem hybrid yang dikaji, peranti P3HT:ZnO memberikan prestasi terbaik dengan 3% nanopartikel ZnO ke dalam komposisi campuran optimum.

Selanjutnya, sintesis sol-jel ZnO telah dijalankan bagi menghasilkan suatu campuran P3HT and ZnO yang lebih baik. Tambahan pula, beberapa pendekatan telah diambil, iaitu dengan mengubah isi kandungan sol dalam campuran, mempelbagaikan suhu pemanasan, dan memasukkan satu lapisan penampan ZnO di antara lapisan aktif dan katod. Rawatan pemanasan yang optimum menawarkan ciri-ciri penyerapan optik yang lebih baik dan permukaan morfologi filem yang lebih seragam dengan menghapuskan liang dan gumpalan besar. Peranan lapisan penampan ZnO dalam sistem campuran tersebut boleh dilihat sebagai suatu ejen yang memudahkan kutipan elektron dari lapisan aktif ke katod. Dapatan kajian ini menunjukkan bahawa prestasi bagi peranti berasaskan P3HT:sol-jel ZnO yang disediakan pada komposisi campuran (0.1 ml sol) dan suhu pemanasan optimum pada 100°C dan mengandungi satu lapisan penampan ZnO, telah meningkat sebanyak 5 kali ganda berbanding dengan peranti berasaskan P3HT:nanopartikel ZnO.

#### **ACKNOWLEDGEMENTS**

First and foremost I would like to thank God for the strength He has given to me that keeps me moving on to accomplish my goal. I would like to thank my family who have continuously inspired, encouraged and supported me in every trial that come to my way throughout my life. Also, I thank them for giving me not just financial, but moral and spiritual support.

I would also like to gratefully acknowledge my supervisor, Dr. Khaulah Sulaiman for her enthusiastic supervision and valuable guidance to me during this research work. This work would not have been possible without her support and assistance. Special thank to my senior, Mr. Fahmi Faraq Muhamad for his precious encouragement, support, and assistance to me. Besides, I am greatly grateful to all the officials, staff members and my labmates from Low Dimensional Materials Research Center, Department of Physics in University of Malaya, for their sincere assistance and support to me in completing this research work. Special thanks also to all my group members especially Mr. Lim Lih Wei, Mrs. Zurianti, Mr. Shahino Mah Abdullah, Mr. Muhamad Saipul and Miss Fadilah for their willingness to share their literature knowledge and invaluable advice to me.

I would also wish to express my gratitude and thanks to University of Malaya for providing the sufficient financial support to me in the form of scholarship and research grants of PS 303/2009C and PS 462/2010B to support my work and to participate in national and international conferences in different places.

Last but no least, I would like to thank all my friends and housemates for their understanding, care and encouragement, particularly Miss Nor Khairiah Za'aba, Miss Siti Hajar, Miss Maisara Othman, Miss Nur Maisarah, Mrs. Noor Hamizah Khanis, and Mr. Paul Lee Chun Hoong who have continuously given me moral and spiritual support when it is most required.

### **RESEARCH PAPERS AND CONFERENCES**

#### A. Published Full Papers (ISI-cited)

- 1. Yusli, M. N., Toong, W. Y., & Sulaiman, K. (2009). Solvent Effect on the thin film formation of polymeric solar cells. *Material Letters*, 63(30), 2691-2694.
- 2. Toong, W. Y., & Sulaiman, K. (2011). Fabrication and morphological characterization of hybrid polymeric solar cells based on P3HT and inorganic nanocrystal blends. *Sains Malaysiana*, 40(1), 43-47.

### **B.** Conference Papers (Non-ISI cited)

- Sulaiman, K., & Toong, W. Y., "Studies of optical and morphological properties on the ZnPc/Gaq3 mixture thin films". Paper presented at 24<sup>th</sup> Regional Conference on Solid State Science & Technology (RCSSST 2008) in Port Dickson, Malaysia.
- Toong, W. Y., & Sulaiman, K., "Fabrication and morphological characterization of hybrid polymeric solar cells based on P3HT and inorganic nanocrystal blends". Paper presented at National Physics Conference (PERFIK 2009) in Malacca, Malaysia.
- Toong, W. Y., & Sulaiman, K., "The fabrication and properties characterization of hybrid polymeric solar cells based on conjugated polymer/inorganic nanoparticles". Paper presented at 3<sup>rd</sup> International Conference on Functional Materials and Devices (ICFMD 2010) in Kuala Terengganu, Malaysia.
- 4. Toong, W. Y., & Sulaiman, K., "The fabrication and properties characterization of hybrid solar cells based on conjugated polymer/inorganic compound". Paper presented at 5<sup>th</sup> International Conference on Technological Advances of Thin Films & Surface Coatings (Thin films and COMPO 2010) in Harbin, China.

# TABLE OF CONTENTS

TABLE OF CONTENTS	vii
LIST OF FIGURES	xi
LIST OF TABLES	xviii
LIST OF SYMBOLS	xx
LIST OF ABBREVIATIONS	xxi
CHAPTER 1: INTRODUCTION	1
1.1 Background of the Research Studies	1
1.2 History of Organic Solar Cells (OSCs)	3
1.3 The Reasons of Investigation on Hybrid Polymer Solar Cells	6
1.4 Research Objectives	9
1.5 Dissertation Outline	10
CHAPTER 2: THEORETICAL BACKGROUND	12
2.1 Overview	12
2.2 Conjugated Polymers	12
2.3 Charge Transport Characteristics of Conjugated Polymers	16
2.4 Electronic Properties of Conjugated Polymers	17
2.5 Doping	20
2.6 Optical Properties of Conjugated Polymers	22
2.7 Donor Material	24
2.7.1 Poly(thiophene)	24
I) Regioregularity	25
II) Solubility	25
III) Regioregular Poly (3-hexylthiophene) (P3HT)	26
2.8 Acceptor Material	27
2.8.1 Inorganic Nanoparticles	27
2.8.2 Physical Properties of Inorganic Nanoparticles	29
I) Optical Properties	29
II) Structural and Morphological Properties	30
III) Electrical Properties	30
2.8.3. Types of Inorganic Nanoparticles Used in This Research Work	31
I) Zinc Oxide	31
II) Titanium Dioxide	32
III) Yttrium Oxide	33

2.9 Sol-Gel Synthesis Route	34
2.10 Hybrid Polymer Solar Cells	35
2.10.1 Basic Working Principles of Hybrid Solar Cells	37
2.10.2 Key Parameters of the Hybrid Solar Cells	38
2.10.3 Types of Device Architectures for Organic Solar Cells	40
I) Single Layer Organic Solar Cell	40
II) Bilayer Solar Cell	41
III) Bulk Heteronjunction (BHJ) Solar Cell	42
CHAPTER 3: EXPERIMENTAL METHODOLOGY	44
3.1 Overview	44
3.2 Chemicals and Materials	44
3.2.1. Chemicals and Solutions Preparation	45
I) P3HT:As-Purchased Inorganic Nanoparticles Blends	45
II) P3HT:As-Synthesized Sol-gel ZnO Blend Solutions	46
3.2.2 Substrates and Electrodes Preparation	48
3.2.3 Substrates Patterning and Cleaning	48
3.3 Thin Films Preparation via Spin Coating Technique	50
3.3.1 P3HT:ZnO Sol-Gel Film Preparation via Thermal Annealing	
Treatment	52
3.4 Devices Fabrication	53
3.4.1 Single Layer and Bulk Heterojunction (BHJ) Structures	53
3.4.2 Aluminum (Al) Electrodes Deposition via Thermal Evaporation	54
3.5 Characterization Techniques	57
3.5.1 Ultraviolet-Visible-Near Infrared (UV-VIS-NIR) Spectrophotometer	57
3.5.2 X-ray Diffraction (XRD) Technique	60
3.5.3 Atomic Force Microscopy (AFM)	64
3.5.4 Field-Emission Scanning Electron Microscopy (FESEM)	66
3.5.5 Surface Profilometer	69
3.5.6 Photovoltaic (PV) Measurement	71
CHAPTER 4: CHARACTERIZATION OF P3HT:ZNO HYBRID THIN FILMS AND SOLAR CELL DEVICES	74
4.1 Overview	74
4.2 Optical Characterization: Ultraviolet-Visible-Near Infrared (UV-Vis-NIR)	_
Spectra Analysis	74
4.3 Structural Characterization: X-ray Diffraction (XRD) Spectra Analysis	84

4.4 Morphological Characterization: Atomic Force Microscopy (AFM) and
Field Emission Scanning Electron Microscopy (FESEM) Analysis
4.4.1 AFM Characterization
4.4.2 FESEM Imaging
4.5 Electrical Characterization: Current Density-Voltage (J-V) Curve Analysis.
CHAPTER 5: HYBRID SOLAR CELLS BASED ON INORGANIC NANOPARTICLES AND P3HT:ZNO ACTIVE LAYERS PREPARED BY SOL-GEL SYNTHESIS ROUTE
5.1 Overview
5.2 Part I: Investigation of Hybrid Solar Cells Based on Various Inorganic
Nanoparticles
5.2.1. Results on P3HT:TiO <sub>2</sub> Blend Films and Their Based Solar Cell
Devices
A. Optical Characterization
B. Structural Characterization
C. Morphological Characterization
D. Electrical Characterization
5.2.2. Results on P3HT:Y <sub>2</sub> O <sub>3</sub> Blend Films and Solar Cell Devices
A. Optical Characterization
B. Structural Characterization
C. Morphological Characterization
D. Electrical Characterization
5.2.3 Comparison of Hybrid Systems Based on Three Different Types of
Inorganic Metal Oxide Nanoparticles
A. Optical Characterization
B. Structural Characterization
C. Morphological Characterization
D. Electrical Characterization
5.3 Part II: The Improvement of P3HT:ZnO Devices by Sol-gel Synthesis
Route
5.3.1 First Approach: Effects of Different Sol Content
A. Optical Characterization
B. Structural Characterization
C. Morphological Characterization

D. Electrical Characterization	149
5.3.2 Second Approach: Effects of Different Annealing Temperature	152
A. Optical Characterization	152
B. Morphological Characterization	154
C. Electrical Characterization	156
5.3.3 Third Approach: Effects of Additional ZnO Buffer Layer	158
A. Morphological Characterization	158
B. Electrical Characterization	160
CHAPTER 6: CONCLUSIONS AND FUTURE WORKS	163
6.1 Conclusions	163
6.2 Future Works	168

## LIST OF FIGURES

Figure 1.01:	Block diagram of research methodology used in this study
Figure 2.01:	The examples of 1) non-conjugated polymers: (i) Polypropylene, (ii) Poly(vinyl alcohol); 2) conjugated polymers: (i) Polyacetylene, (ii) Polythiophene (Skotheim, et al., 1998)
Figure 2.02:	(a) The structure of ethylene comprises of $\sigma$ bonds which formed from the three sp <sup>2</sup> -hybridized orbitals on each carbon atom. (b) The formation of $\pi$ bond due to the overlap of the unhybridized $p_z$ orbital. (c) A cutaway view of the whole $\sigma$ and $\pi$ system within the ethylene molecule (Hari Singh Nalwa, 2002).
Figure 2.03:	The schematic diagram of HOMO and LUMO bands
Figure 2.04:	Schematic representation of intrachain charge diffusion (left) and interchain charge diffusion (right) in polyacetylene
Figure 2.05:	Potential energy as a function of bond length alternation for the two categories of conjugated polymers are exhibited for (a) a degenerate ground state conjugated polymer, <i>trans</i> -polyacetylene; (b) a non-degenerate ground state conjugated polymer (in the given example is poly-para-phenylene (PPP))
Figure 2.06:	Schematic structure and energy diagram for solitons in conjugated polymer is shown
Figure 2.07:	Schematic structure and band diagrams for excitations in non- degenerate ground state conjugated polymers. Allowed optical transitions are exhibited by the blue-colored dashed arrows
Figure 2.08:	Removal of two electrons (p-type doping) from a polyacetylene chain produces two radical cations. The combination of both radicals forms a spinless di-cation
Figure 2.09:	Removal of two electrons (p-type doping) from a polythiophene chain produces bipolaron. Bipolaron moves as a unit up and down the polymer chain, which is responsible to the electrical properties of conjugated polymers
Figure 2.10:	A coplanar $\pi$ -orbitals polythiophene (top); a twisted substituted polythiophene (bottom) (Skotheim, et al., 1998)
Figure 2.11:	The chemical structure of monomer repeating unit of PTs
Figure 2.12:	The differences between regiorandom and regioregular PTs in aspect of chain structure and charge transport characteristics

xi

Figure 2.13:	The chemical structure of P3HT
Figure 2.14:	The structures and shapes of the inorganic nanoparticles that are widely used in hybrid polymer solar cells
Figure 2.15:	Energy dispersion for the (a) bulk semiconductor compared with that of (b) the nanoparticles (Dhlamini, et al., 2008)
Figure 2.16:	The chemical structure of ZnO
Figure 2.17:	The chemical structure of TiO <sub>2</sub>
Figure 2.18:	The chemical structure of Y <sub>2</sub> O <sub>3</sub>
Figure 2.19:	Schematic structure of hybrid solar cell
Figure 2.20:	The working principle of hybrid polymer solar cell consisting of an electron donor and acceptor pair
Figure 2.21:	The current density-voltage curve (J-V curve) of a hybrid solar cell under illuminated condition (dash line)
Figure 2.22:	(a) The basic structure of a single layer solar cell. (b) Schematic of a single layer solar cell with a Schottky contact at the lower function electrode B contact. Photogenerated excitons can only be dissociated within a narrow deplection layer, and thus the device is exciton diffusion limited
Figure 2.23:	The basic structure of a bilayer solar cell. (b) Schematic of a bilayer heterojunction solar cell. The donor (D) contacts the higher work function electrode A and the acceptor (A) contacts the lower work function electrode B, in order to achieve charge carrier collection, respectively. Excitons can only be dissociated within the region at the D/A interface.
Figure 2.24:	(a) The basic structure of a bulk heterojunction solar cell. (b) Schematic of a bulk heterojunction solar cell device. The excitons can be dissociated throughout the volume of material as the D is well blended with A
Figure 3.01:	Pristine solutions and the P3HT:inorganic nanoparticles blend solutions
Figure 3.02:	P3HT:sol-gel ZnO blend solutions
Figure 3.03:	ITO substrates patterning
Figure 3.04:	The spin coating machine which is used for thin films deposition

Figure 3.05:	Schematic representation of the spin coating technique	51
Figure 3.06:	The flow chart for the preparation of the P3HT:sol-gel ZnO films	52
Figure 3.07:	The device construction of solar cells based on different devices geometry and hybrid systems	54
Figure 3.08:	Thermal evaporation system for Al electrode deposition. The inset shows the designed shadow mask used in this work	55
Figure 3.09:	The schematic diagram of the evaporation system arrangement within the vacuum chamber	55
Figure 3.10:	Possible electronic transitions of $\pi$ , $\sigma$ or n electrons	58
Figure 3.11:	Photograph of Jasco V-570 UV-VIS-NIR Spectrophotometer	59
Figure 3.12:	Schematic diagram of the components of a UV-VIS-NIR spectrophotometer	60
Figure 3.13:	The diffraction pattern of X-rays by planes of atoms	61
Figure 3.14:	(a) Photograph of the XRD instrument (Bruker AXS). (b) The basic components of a X-ray diffractometer	62
Figure 3.15:	Schematic diagram of an atomic force microscope	64
Figure 3.16:	Photograph of Veeco Dimension 3000 AFM instrument	66
Figure 3.17:	Field-emission scanning electron microscope (FESEM)	67
Figure 3.18:	Principle features of a SEM instrument	68
Figure 3.19:	(a) The schematic diagram of a contact profilometer. (b) Resultant surface profile that is generated based on the tip deflection.	70
Figure 3.20:	KLA Tensor P-6 surface profilometer for film thickness measurement.	70
Figure 3.21:	(a) An Oriel 67005 solar simulator. (b) The internal structure of the Oriel solar simulator.	72
Figure 3.22:	(a) A Keithley 236 SMU instrument. (b) A solar cell device connected to its appropriate terminals under I-V measurement	73
Figure 4.01:	Absorption coefficient of pristine P3HT, ZnO and P3HT:ZnO blend films with different contents of ZnO nanoparticles. The inset shows the variation of maximum absorption coefficient peak values, $\alpha_{max}$ and film thickness, t as a function of blend composition	74

Figure 4.02:	The pre-estimated $E_g$ of the pristine (a) P3HT film and (b) ZnO nanoparticles film using plots of $d\ln(\alpha hv)/dhv$ versus hv	79
Figure 4.03:	Plots of $ln(\alpha hv)$ versus $ln(hv - E_g)$ to determine the n value for (a) P3HT and (b) ZnO nanoparticles films, respectively	80
Figure 4.04:	Plots of $(\alpha hv)^2$ against hv for (a) P3HT and (b) ZnO films	81
Figure 4.05:	The typical energy band diagram of (a) P3HT and (b) ZnO nanoparticles films where the conduction band of ZnO is tunable due to the variation in nanoparticles size	82
Figure 4.06:	Plots of $d\ln(\alpha h\nu)/dh\nu$ versus hv to pre-estimate the E <sub>g</sub> of the P3HT:ZnO blend films with different contents of ZnO	83
Figure 4.07:	Plots of of $(\alpha hv)^2$ against hv for P3HT:ZnO blend films with different contents of ZnO	84
Figure 4.08:	The XRD pattern of ZnO nanoparticles in powder form	85
Figure 4.09:	Williamson-Hall plots to determine the microstrain of ZnO	87
Figure 4.10:	The XRD spectra of pristine P3HT and P3HT:ZnO blend films. The inset illustrates the orientation of P3HT crystallites with respect to the substrate	87
Figure 4.11:	Three-dimensional AFM images by $10 \times 10 \ \mu m^2$ scan for (a) pristine P3HT and the blend films in different compositions with (b) 1%, (c) 2%, (d) 3%, (e) 4%, (f) 5%, and (g) 10% ZnO	93
Figure 4.12:	2-dimensional AFM images of the (a) pristine P3HT and its blends with (b) 1%, (c) 2%, (d) 3%, (e) 4%, (f) 5%, and (g) 10% ZnO.	97
Figure 4.13:	The schematic illustration of some possible morphologies that most likely have been achieved for the P3HT:ZnO blends incorporated with different amount of ZnO contents	99
Figure 4.14:	FESEM images of (a) P3HT and its blends with (b) 1%, (c) 3%, (d) 5% and (e) 10% ZnO ((e(ii) shows the focused zone area of image (e)).	101
Figure 4.15:	The FESEM images of pristine ZnO nanoparticles film	101
Figure 4.16:	The current density–voltage (J-V) characteristics of solar cell devices based on pristine P3HT and P3HT:ZnO blends in different blend compositions under dark condition	102
Figure 4.17:	Current density-voltage (J-V) characteristic curves of the solar cell devices under light illumination. The inset displays an equivalent circuit diagram of solar cells which consists of series	

	resistance, R <sub>s</sub> and shunt resistance, R <sub>sh</sub>	10
Figure 4.18:	The schematic energy band diagram of ITO/PEDOT:PSS/P3HT:ZnO/Al devices	10
Figure 4.19:	The variation of (i) $J_{sc}$ and $V_{oc},$ (ii) FF and $\eta$ with the blend composition.	10
Figure 4.20:	The variation of $R_{sh}$ and $R_s$ with the blend composition	10
Figure 5.01:	Absorption coefficient of P3HT:TiO <sub>2</sub> blend films with different contents of TiO <sub>2</sub> nanoparticles. The inset shows the variation of maxmimum absorption coefficient peak values, $\alpha_{max}$ and film thickness, t as a function of TiO <sub>2</sub> contents	11
Figure 5.02:	The XRD patterns of (i) $TiO_2$ in powder form; (ii) pristine P3HT and P3HT:TiO <sub>2</sub> blend films	11
Figure 5.03:	AFM images in 2D and 3D views for (a) pristine P3HT and P3HT: $TiO_2$ blend films with (b) 1%, (c) 2%, (d) 3%, (e) 4%, (f) 5%, and (g) 10% $TiO_2$	11
Figure 5.04:	The J-V plots for P3HT:TiO <sub>2</sub> solar cells with different blend compositions under light illumination	11
Figure 5.05:	Variations in the device parameters for (i) $J_{sc}$ and $V_{oc}$ (ii) $R_s$ and $R_{sh}$ , (iii) FF and $\eta$ as a function of blend composition	11
Figure 5.06:	The optical spectra for the P3HT: $Y_2O_3$ blend films. The inset indicates the variation of $\alpha_{max}$ and film thickness as a function of $Y_2O_3$ content in P3HT: $Y_2O_3$ blends	11
Figure 5.07:	The XRD spectra of (i) Y <sub>2</sub> O <sub>3</sub> nanopowder; (ii) P3HT:Y <sub>2</sub> O <sub>3</sub> blend films	12
Figure 5.08:	The AFM images for (a) pristine P3HT and the blend films with (b) 1%, (c) 2%, (d) 3%, (e) 4%, (f) 5%, and (g) 10% $Y_2O_3$	12
Figure 5.09:	The J-V plots for pristine P3HT and P3HT:Y <sub>2</sub> O <sub>3</sub> blend devices	12
Figure 5.10:	Variations in the device parameters for (i) $J_{sc}$ and $V_{oc}$ , (ii) $R_s$ and $R_{sh}$ , (iii) FF and $\eta$ as a function of blend composition	12
Figure 5.11:	(i) Plots of $(\alpha hv)^2$ against hv for ZnO, TiO <sub>2</sub> and Y <sub>2</sub> O <sub>3</sub> films, the inset shows the plots of ln( $\alpha hv$ ) versus ln( $hv - E_g$ ) to determine the type of electronic transition for the nanoparticles. (ii) Absorption coefficient spectra of the P3HT:nanoparticles blends; the inset shows the estimated $E_g$ of the blends	12
Figure 5.12:	The XRD spectra of P3HT:nanoparticles blend films	12

Figure 5.13:	The AFM images of P3HT:nanoparticles blend films in 3D and 2D views for (i) P3HT:ZnO, (ii) P3HT:TiO <sub>2</sub> , and (iii) P3HT:Y <sub>2</sub> O <sub>3</sub> film.
Figure 5.14:	FESEM images of the (a) pristine inorganic metal oxide nanoparticles, and (b) P3HT:nanoparticles blend films with ZnO (I), $TiO_2$ (II) and $Y_2O_3$ (III)
Figure 5.15:	Comparison of the J-V characteristics of the solar cells based on three different types of P3HT:metal oxide nanoparticles hybrid systems under white light illumination
Figure 5.16:	An inferred schematic energy band diagram for the P3HT:inorganic nanoparticles hybrid systems, placed between anode ITO and cathode Al.
Figure 5.17:	Absorption coefficient spectra of pristine P3HT, sol-gel derived ZnO and P3HT:sol gel ZnO blend films with different sol contents. The inset indicates the variation of $\alpha_{max}$ and film thickness as a function of sol content. Also, the comparison between P3HT:ZnO NPs and P3HT:sol-gel ZnO films is shown.
Figure 5.18:	The plots of $(\alpha hv)^2$ against hv for P3HT:sol gel ZnO blend films with different sol contents
Figure 5.19:	The XRD patterns of P3HT:sol-gel ZnO blend films with different sol contents as well as XRD patterns of bared ZnO NPs deposited film and sol-gel derived ZnO films
Figure 5.20:	XRD parameters of blend films as a function of different sol contents, namely: (i) FWHM, (ii) crystallite size and (iii) dislocation density corresponding to (100), (002), and (110) planes
Figure 5.21:	The AFM images of P3HT:sol-gel ZnO blend films with (a) 0.05 ml, (b) 0.1 ml, (c) 0.2 ml, and (d) 0.3 ml sol content
Figure 5.22:	AFM images by $10 \times 10 \ \mu m^2$ scan in both 2D and 3D views of (i) P3HT:ZnO NPs and (ii) P3HT:sol gel ZnO blend films
Figure 5.23:	The FESEM images of P3HT:sol-gel ZnO films with (a) 0.05 ml, (b) 0.1 ml, (c) 0.2 ml, and (d) 0.3 ml sol
Figure 5.24:	The comparison of FESEM images between (i) P3HT:ZnO NPs film and (ii) P3HT:sol-gel ZnO film. The inset shows the surface micrograph of (i) bare ZnO NPs film and (ii) bare sol-gel derived ZnO film.
Figure 5.25:	The J-V plots for P3HT:sol-gel ZnO solar cells with different sol contents in blends

Figure 5.26:	Variations in the device parameters for (i) $J_{sc}$ and $V_{oc}$ , (ii) $R_s$ and $R_{sh}$ , (iii) FF and $\eta$ as a function of sol content in blends	149
Figure 5.27:	Photovoltaic comparison for P3HT:sol gel ZnO and P3HT:ZnO NPs films	151
Figure 5.28:	The optical spectra of P3HT:sol-gel ZnO films annealed at different temperatures, $T_a$ . The inset indicates the variation of $\alpha_{max}$ and film thickness as a function of $T_a$	153
Figure 5.29:	The plots of $(\alpha hv)^2$ against hv for P3HT:sol gel ZnO blend films annealed at different T <sub>a</sub>	153
Figure 5.30:	The AFM images in 2D and 3D of P3HT:sol gel ZnO films annealed at different $T_a$ of (a) 75 °C, (b) 100 °C, (c) 150 °C, (d) 175 °C	155
Figure 5.31:	The J-V plots for P3HT:sol gel ZnO solar cells fabricated from active layers annealed at different $T_a$	156
Figure 5.32:	Variation in the device parameters for (i) $J_{sc}$ and $V_{oc}$ (ii) $R_s$ and $R_{sh}$ , (iii) FF and $\eta$ as a function of annealing temperature	157
Figure 5.33:	Morphological characteristics of the P3HT:sol-gel ZnO film (i) without and (ii) with an additional ZnO buffer layer (BL) via AFM imaging	159
Figure 5.34:	The comparison of the J-V characteristics of the solar cell devices without and with an additional ZnO buffer layer	160

## LIST OF TABLES

		Page
Table 1.1:	A list of development in the organic solar cells	5
Table 3.1:	Blend compositions and the respectively masses of P3HT:inorganic nanoparticles blends	45
Table 3.2:	Blend compositions of P3HT:sol-gel ZnO	47
Table 3.3:	The deposition parameters of Al electrodes	56
Table 3.4:	Parameters of UV-VIS-NIR spectrum	60
Table 3.5:	Scanning parameters of XRD measurement	63
Table 3.6:	Parameters of the AFM measurement	66
Table 3.7:	Scanning parameters of film thickness measurement	71
Table 4.1:	The comparison of the absorption coefficient peak values and the corresponding wavelength positions for pristine P3HT and P3HT:ZnO blends	76
Table 4.2:	The values of average thickness for pristine P3HT, ZnO and P3HT:ZnO blend films	76
Table 4.3:	The values of $E_g$ for pristine P3HT, ZnO and P3HT:ZnO blend films based on two different types of functions, in which the later one gives a more precise estimation value of $E_g$	84
Table 4.4:	Summary of the XRD properties of the P3HT:ZnO nanoparticles blend films with different ZnO content	89
Table 4.5:	The mean surface roughness and root-mean-square roughness of the films obtained from AFM for Figure 4.11	94
Table 4.6:	The comparison of device characteristics parameters for pristine P3HT and P3HT:ZnO solar cells with different ZnO concentration.	104
Table 4.7:	The variation of $R_{sh}$ and $R_s$ with the blend composition	109
Table 5.1:	Summaries of the $\alpha_{max}$ values together with the corresponding wavelength positions, $\lambda$ , film thickness, t and estimated $E_g$ for pristine P3HT and P3HT:TiO <sub>2</sub> blends	112
Table 5.2:	Summaries of the Bragg diffraction angles and film roughnesses (obtained from AFM images) of pristine P3HT and P3HT: $TiO_2$ blends	113
Table 5.3:	The comparison of device characteristics parameters for P3HT:TiO <sub>2</sub> solar cells	117

Table 5.4:	Summaries of the $\alpha_{max}$ values together with the corresponding wavelength positions, $\lambda$ , film thickness, t and estimated $E_g$ for pristine P3HT and P3HT:Y <sub>2</sub> O <sub>3</sub> blends	11
Table 5.5:	Summaries of the Bragg diffraction angles and film roughnesses of pristine P3HT and P3HT:Y <sub>2</sub> O <sub>3</sub> blends	12
Table 5.6:	The comparison of device characteristics parameters for P3HT and P3HT: $Y_2O_3$ solar cells	124
Table 5.7:	Variation in the J-V characteristics of P3HT: metal oxide nanoparticles hybrid solar cells	13
Table 5.8:	The comparison of $\alpha_{max}$ values, the corresponding wavelength positions, average film thicknesses and estimated $E_g$ for P3HT:sol gel ZnO blends with different sol contents	13
Table 5.9 (i) & (ii):	Summaries of the XRD parameters of P3HT:sol gel ZnO blend films with different sol contents	14
Table 5.10:	Surface roughness values of the blend films obtained from AFM	14
Table 5.11:	The comparison of device characteristics parameters for P3HT:sol-gel ZnO solar cells	14
Table 5.12:	The comparison of the $\alpha_{max}$ values, the corresponding wavelength positions, average film thicknesses and estimated $E_g$ for the P3HT:sol gel ZnO films annealed at different $T_a$	15
Table 5.13:	Surface roughness values of P3HT:sol gel ZnO films annealed at different $T_a$	15
Table 5.14:	The comparison of device characteristics parameters for P3HT:sol gel ZnO solar cells	15
Table 5.15:	Surface roughness values of the films obtained from AFM	16
Table 5.16:	Device characteristics parameters of P3HT:sol gel ZnO solar cells with ZnO buffer layer spun at different spin speed	16
Table 5.17:	Device characteristics parameters of P3HT:sol gel ZnO solar cells	16

# LIST OF SYMBOLS

>	Less than
<	More than
π	Pi
σ	Sigma
Т	Transmittance
А	Absorbance
Io	Light intensities
E	Energy
λ	Wavelength
d	Interatomic spacing distance
θ	Diffraction angle
Eg	Energy gap
$\Delta \mathbf{r}$	Bond length alternation
I <sub>SC</sub>	Short-circuit current
V <sub>OC</sub>	Open circuit voltage
P <sub>max</sub>	Maximum power
Pout	Output power
V <sub>max</sub>	Voltage at maximum power
I <sub>max</sub>	Current at maximum power
P <sub>in</sub>	Input power
FF	Fill factor
η	Power conversion efficiency
α	Absorption coefficient
t	Film thickness
В	Full width at half maximum
t <sub>c</sub>	Crystallite size
С	Scherrer constant
3	Strain
$\Lambda_{\rm E}$	Exciton diffusion length
$D_E$	Exciton diffusion coefficient
T <sub>E</sub>	Exciton lifetime
R <sub>a</sub>	Mean surface roughness
V <sub>on</sub>	Turn-on voltage
J <sub>sc</sub>	Short-circuit current density
R <sub>sh</sub>	Shunt resistance
R <sub>s</sub>	Series resistance
D/A	Donor/Acceptor
J-V	Current density-voltage
ბ 	Dislocation density
la	Annealing temperature

## LISTS OF ABBREVIATIONS

BHJ	Bulk heterojunction
1-D	One dimensional
AFM	Atomic force microscopy
Ag	Silver
Al	Aluminum
AM 1.5	Air mass 1.5
Au	Gold
BL	Buffer layer
C <sub>60</sub>	Buckminsterfullerene
Ca	Calcium
CB	Conduction band
CdSe	Cadmium selenide
CHCl <sub>3</sub>	Chloroform
Cu	Copper
DEA	Diethanolamine
EDX	X-ray spectroscopy
FESEM	Field-effect scanning electron microscopy
FWHM	Full width at half maximum
HC1	Hydrochloric acid
HE	High energy
HOMO	Highest eccupied molecular orbital
	Indium tin ovido
	Indium un Oxide
JCPDS	Joint committee on powder diffraction standards
LE	Low energy
LUMO	Lowest unoccupied molecular orbital
MEH-PPV	Poly[2-methoxy-5-(2'-ethylhexyloxy)-p-phenylene vinylene]
MgPh	Magnesium phthalocyanine
NPs	Nanoparticles
OSCs	Organic solar cells
P3HT	Poly(3-hexylthiophene)
PbS	Plumbum sulfide
PCBM.	[6,6]-phenyl- $C_{61}$ -butyric acid methyl ester
PCE	Power conversion efficiency
PEDOT:PSS	Poly(3,4-ethylenedioxythiophene) poly(styrenesulfonate)
PPP	Poly-para-phenylene
PT	Poly(thiophene)
PV	Photovoltaic
RMS	Root-mean-square
rpm	Rotations per minute
SMU	Source measuring unit
STC	Standard test condition
TiO <sub>2</sub>	Titanium dioxide
UV-VIS-NIR	Ultraviolet-visible-near-infrared
VB	valence band
XRD	X-ray diffraction
7nO	Zinc oxide